Approved for use through 07/31/2006. OMB 0651-0031 U.S. Patent and Trademark Office, U.S. DEPARTMENT OF COMMERCE Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a valid OMB control number. Application Number 10/625,068 TRANSMITTAL Filing Date July 22, 2003 **FORM** First Named Inventor Arup Bhattacharyya Art Unit 2829 **Examiner Name** Christian D. Wilson (to be used for all correspondence after initial filing) Attorney Docket Number MI22-2362 Total Number of Pages in This Submission

ENCLOSURES (Check all that apply)								
<b>✓</b>	Fee Trans	smittal Form		Drawing(s)			After Allowance Communication to TC	
	✓ Fe	ee Attached		Licensing-related Papers			Appeal Communication to Board of Appeals and Interferences	
	Amendment/Reply After Final Affidavits/declaration(s)  Extension of Time Request Express Abandonment Request Information Disclosure Statement  Certified Copy of Priority Document(s) Reply to Missing Parts/ Incomplete Application Reply to Missing Parts under 37 CFR 1.52 or 1.53		U.S. F	Petition Petition to Convert to a Provisional Application Power of Attorney, Revocation Change of Correspondence Address Terminal Disclaimer Request for Refund CD, Number of CD(s) Landscape Table on CD Remarks U.S. Patent No. 6,908,798 Issued: June 21, 2005		Appeal Communication to TC (Appeal Notice, Brief, Reply Brief)  Proprietary Information  Status Letter  Other Enclosure(s) (please Identify below):  Return Receipt Postcard; Check - \$100.00; Request for Certificate of Correction; Certificate of Correction  Certificate  MAY 2 6 2006		
	<del></del>	SIGNA	TURE	OF APPLICANT, ATT	ORNEY, C	R AG	ENT Of Correction	
Firm Name Wells St. John P.S.				· · ·				
Signature								
Printed name David G. La		David G. Latwesen, Ph.D.	i. Latwesen, Ph.D.					
Date		5/22/06			Reg. No.	38,53	3	
		·		<del></del>				

Typed or printed name

CERTIFICATE OF TRANSMISSION/MAILING

CERTIFICATE OF TRANSMISSION/MAILING

I hereby certify that this correspondence is being facsimile transmitted to the USPTO or deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on the date shown below:

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Terri Lynn Boyd-Davis

Date

5-22-06

This collection of information is required by 37 CFR 1.5. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.11 and 1.14. This collection is estimated to 2 hours to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

PTO/SB/17 (01-06) Approved for use through 07/31/2006, OMB 0651-0032

U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMET  Under the previous Reduction Act of 1995 no persons are required to respond to a collection of information unless it displays a valid OMB control num								
pursuant to the Consolidated Appropriations Act, 2005 (H.R. 4818).			Complete if Known					
			Application Number	10/625,068				
FEE TRA	NSIVI	IIIAL	Filing Date	July 22, 2003				
For F	Y 2006		First Named Inventor	Arup Bhattacharyya	a			
Applicant claims small entity	· atatua Caa	27 OED 4 27	Examiner Name Christian D. Wilson					
		37 CFR 1.27	Art Unit	2829				
TOTAL AMOUNT OF PAYMEN	r (\$)	100.00	Attorney Docket No.	MI22-2362				
METHOD OF PAYMENT (ch	eck all that a	apply)						
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FEE CALCULATION (All the	fees belov	v are due upon f	iling or may be subj	ect to a surcharge.)				
1. BASIC FILING, SEARCH,								
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2. EXCESS CLAIM FEES Fee Description				Fee (\$)	Small Entity Fee (\$)			
Each claim over 20 (inclu	ding Reissue	es)		50	25			
Each independent claim o		ling Reissues)		200	100			
Multiple dependent claim				360	180			
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3. APPLICATION SIZE FEE								
If the specification and drawings exceed 100 sheets of paper (excluding electronically filed sequence or computer listings under 37 CFR 1.52(e)), the application size fee due is \$250 (\$125 for small entity) for each additional 50								
sheets or fraction thereo	sheets or fraction thereof. See 35 U.S.C. 41(a)(1)(G) and 37 CFR 1.16(s).							
	ra Sheets / 5		<u>ch additional 50 or frác</u> (round up to a whole		<u>Fee Paid (\$)</u>			
4. OTHER FEE(S)	/`				Fage Daid (t)			
Non-English Specification, \$130 fee (no small entity discount)								
Other (e.g., late filing surcharge): Certificate of Correction 100.00								

SUBMITTED BY			
Signature	M.	Registration No. (Attorney/Agent) 38,533	Telephone (509) 624-4276
Name (Print/Type)	David G. Latwesen, Ph.D.		Date 5/27/06

This collection of information is required by 37 CFR 1.136. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 30 minutes to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.



Patent No	6,908,798 B1			
Patent Issue Date				
Application Serial No				
Filing Date				
Assignee				
Inventorship	Arup Bhattacharyya			
Attorney's Docket No	MI22-2362			
Title: "Methods of Making Semiconductor-On-Insulator Thin Film Transistor				
Constructions"				

## REQUEST FOR CERTIFICATE OF CORRECTION OF PATENT FOR APPLICANT MISTAKES and PTO MISTAKES (37 C.F.R. §§ 1.322(a) and 1.323)

To:

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

ATTN:

Decision and Certificate of Correction
Branch of the Patent Issue Division

From:

David G. Latwesen, Ph.D. (Tel. 509-624-4276; Fax 509-838-3424)

Wells St. John P.S.

601 W. First Avenue, Suite 1300

Spokane, WA 99201-3828

Sir:

It is hereby requested that a Certificate of Correction be issued with respect to Patent No. 6,908,798 B1, granted June 21, 2005, in accordance with the Certificate of Correction form attached hereto in duplicate.

It is noted that errors appear in this patent of a typographical nature of character, as more fully described below. The errors occurred in good faith. Correction thereof does not involve such changes in the patent as would constitute new matter or would require re-examination.

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Other errors listed on the Certificate of Correction form were apparently incurred through the fault of the PTO as will be disclosed by the records of files in the Office.

Attached hereto, in duplicate, is Form PTO-1050, with at least one copy being suitable for printing.

The exact page and line number where the errors occur in the application file are:

- Page 5, paragraph [0009], line 10 in the Specification/Col. 3, line
   22 in the issued patent;
- Page 7, paragraph [0016], line 1 in the Specification/Col. 4, line20 in the issued patent.

Enclosed is a check in the amount of \$100.00, as required by 37 CFR 1.20(a).

Respectfully submitted,

By:

David G. Latwesen, Ph.D.

Reg. No. 38,533

Page \_ 1 \_ of \_ 1

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## UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO.

: 6,908,798 B1

APPLICATION NO.: 10/625,068

ISSUE DATE

: June 21, 2005

INVENTOR(S)

Arup Bhattacharyya

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In the References Cited:

Col. 2, line 14 -

Replace "Kim, C.H. et al., "A New High -Performance Poly3-Si TFT" With --Kim, C.H. et al, "A New High -Performance Poly-Si TFT--

In the Specification:

Col. 2, line 44 -

Replace ""High Performance Sub-100 nm Si TFT by Pattern-" With -- "High Performance Sub-100 nm Si TFT by Pattern---

Col. 2. line 54 -

Replace "islands for device channel regions. Nickelinduced-lateral" With --islands for device channel regions. Nickel-induced-lateral---

Col. 3, line 22 -

Replace "Digest, 2002, 00. 98-99; and Huang, L. J. et al.," With -- Digest, 2002, pp. 98-99; and Huang, L. J. et al., --

Col. 4, line 20 -

Replace "FIG. 2 is a view of the FIG. 1 wafer shown at a processing" With --FIG. 2 is a view of the FIG. 1 fragment shown at a processing--

Col. 10, line 66 -

Replace "similar numbering will be used as is used above In" With --similar numbering will be used as is used above in--

MAILING ADDRESS OF SENDER (Please do not use customer number below):

Wells St. John P.S. 601 W. 1st Avenue, Suite 1300 Spokane, WA 99201

This collection of information is required by 37 CFR 1.322, 1.323, and 1.324. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 1.0 hour to complete, including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, U.S. Department of Commerce, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Attention Certificate of Corrections Branch, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450.

Page \_\_1\_ of \_\_1\_

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## UNITED STATES PATENT AND TRADEMARK OFFICE. CERTIFICATE OF CORRECTION

PATENT NO.

: 6,908,798 B1

APPLICATION NO.: 10/625,068

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INVENTOR(S)

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